

September 1983 Revised January 2005

MM74HC132

Quad 2-Input NAND Schmitt Trigger

General Description

The MM74HC132 utilizes advanced silicon-gate CMOS technology to achieve the low power dissipation and high noise immunity of standard CMOS, as well as the capability to drive 10 LS-TTL loads.

The 74HC logic family is functionally and pinout compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

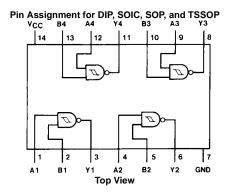
- Typical propagation delay: 12 ns
- Wide power supply range: 2V-6V
- Low quiescent current: 20 µA maximum (74HC Series)
- Low input current: 1 µA maximum
- Fanout of 10 LS-TTL loads
- Typical hysteresis voltage: 0.9V at V_{CC}=4.5V

Ordering Code:

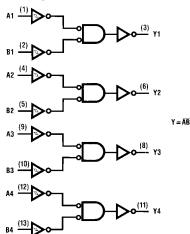
Order Number	Package Number	Package Description
MM74HC132M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC132MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC132SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC132MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC132N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. (Tape and Reel not available in N14A.) Pb-Free package per JEDEC J-STD-020B.

Connection Diagram



Logic Diagram



Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V_{CC}) -0.5 to +7.0V

DC Input Voltage (V_{IN}) -1.5 to $V_{CC} + 1.5V$ DC Output Voltage (V_{OUT}) -0.5 to V_{CC} +0.5V

Clamp Diode Current (I_{IK}, I_{OK}) ±20 mA DC Output Current, per pin (I_{OUT}) ±25 mA

DC V_{CC} or GND Current, per pin (I_{CC}) ±50 mA Storage Temperature Range (T_{STG}) $-65^{\circ}C$ to $+150^{\circ}C$

Power Dissipation (P_D)

600 mW (Note 3) S.O. Package only 500 mW

Lead Temperature (T_L)

(Soldering 10 seconds) 260°C

Recommended Operating Conditions

Units Supply Voltage (V_{CC}) 6 DC Input or Output Voltage ٧ V_{CC} (V_{IN}, V_{OUT})

°С Operating Temperature Range (T_A) -40+125

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground. Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

0	B	Conditions	V	T _A = 25°C		$T_A = -40 \text{ to } 85^{\circ}\text{C}$ $T_A = -40 \text{ to } 125$		Units
Symbol	Parameter	Conditions	v _{cc}	Тур	Guaranteed Limits			
V _{T+}	Positive Going	Min	2.0V		1.0	1.0	1.0	V
	Threshold Voltage		4.5V		2.0	2.0	2.0	V
			6.0V		3.0	3.0	3.0	V
		Max	2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V _{T-}	Negative Going	Min	2.0V		0.3	0.3	0.3	V
	Threshold Voltage		4.5V		0.9	0.9	0.9	V
			6.0V		1.2	1.2	1.2	V
		Max	2.0V		1.0	1.0	1.0	V
			4.5V		2.2	2.2	2.2	V
			6.0V		3.0	3.0	3.0	V
V _H	Hysteresis Voltage	Min	2.0V		0.2	0.2	0.2	V
			4.5V		0.4	0.4	0.4	V
			6.0V		0.5	0.5	0.5	V
		Max	2.0V		1.0	1.0	1.0	V
			4.5V		1.4	1.4	1.4	V
			6.0V		1.5	1.5	1.5	V
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IH}$ or V_{IL}	2.0V	2.0	1.9	1.9	1.9	V
	Output Voltage	$ I_{OUT} \le 20 \mu A$	4.5V	4.5	4.4	4.4	4.4	V
		$V_{IN} = V_{IH}$ or V_{IL}	6.0V	6.0	5.9	5.9	5.9	V
		$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$ or V_{IL}	2.0V	0	0.1	0.1	0.1	V
	Output Voltage	$ I_{OUT} \le 20 \mu A$	4.5V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH}$ or V_{IL}	6.0V	0	0.1	0.1	0.1	V
		$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input Current	V _{IN} = V _{CC} or GND	6.0V		±0.1	±1.0	±1.0	μА
I _{CC}	Maximum Quiescent	V _{IN} = V _{CC} or GND	6.0V		2.0	20	40	μА
	Supply Current	I _{OUT} = 0 μA						

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5V$ and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage curvature of the V_{IH} value at V_{IH} value rent (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 15$ pF, $t_r = t_f = 6$ ns

Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PHL} , t _{PLH}	Maximum Propagation Delay		12	20	ns

AC Electrical Characteristics

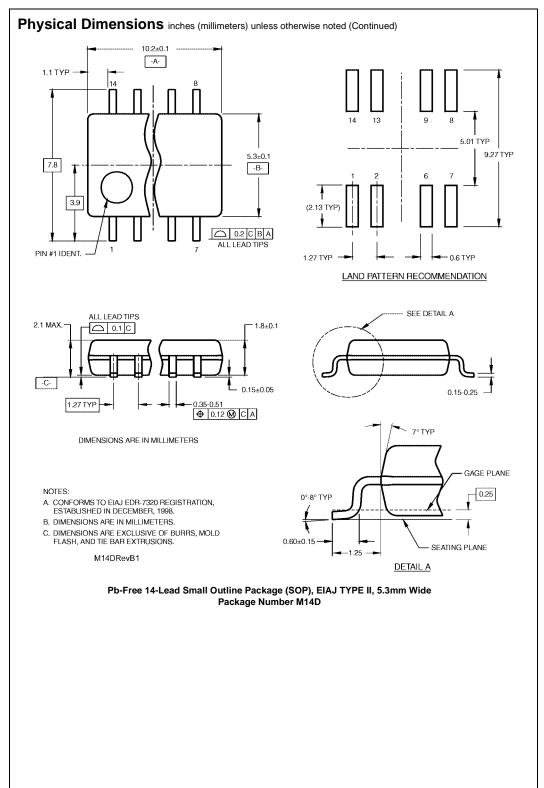
 V_{CC} = 2.0V to 6.0V, C_L = 50 pF, $t_{\rm f}$ = $t_{\rm f}$ = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	v _{cc}	T _A = 25°C		T _A = -40 to 85°C	T _A = -55 to 125°C	Units	
				Тур	p Guaranteed Limits				
t_{PHL} , t_{PLH}	Maximum		2.0V	63	125	158	186	ns	
	Propagation Delay		4.5V	13	25	32	37	ns	
			6.0V	11	21	27	32	ns	
t _{TLH} , t _{THL}	Maximum Output		2.0V	30	75	95	110	ns	
	Rise and Fall Time		4.5V	8	15	19	22	ns	
			6.0V	7	13	16	19	ns	
C _{PD}	Power Dissipation	(per gate)		130				pF	
	Capacitance (Note 5)								
C _{IN}	Maximum Input Capacitance				5	10	10	pF	

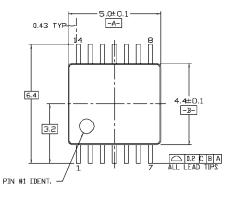
Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.

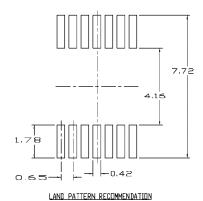
Physical Dimensions inches (millimeters) unless otherwise noted $\frac{0.335 - 0.344}{(8.509 - 8.738)}$ LEAD NO. 1 IDENT 0.010 MAX (0.254) $\frac{0.150 - 0.157}{(3.810 - 3.988)}$ $\frac{0.053 - 0.069}{(1.346 - 1.753)}$ $\frac{0.010 - 0.020}{(0.254 - 0.508)}$ 8° MAX TYP ALL LEADS $\frac{0.004 - 0.010}{(0.102 - 0.254)}$ SEATING PLANE 0.014 0.008 - 0.010 (0.203 - 0.254) TYP ALL LEADS 0.050 (1.270) TYP $\frac{0.014 - 0.020}{(0.356 - 0.508)} \text{ TYP}$ 0.016 - 0.050 (0.406 - 1.270) TYP ALL LEADS 0.004 (0.102) ALL LEAD TIPS 0.008 (0.203) TYP M14A (REV h)

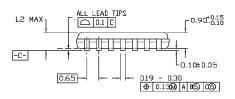
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M14A

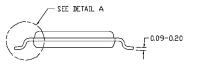


Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





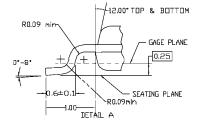




NOTES:

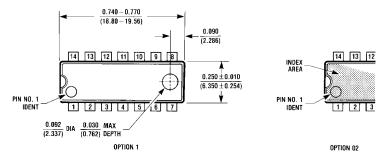
- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB_ REF NOTE 6, DATED 7/93
- B. DIMENSIONS ARE IN MILLIMETERS
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1982

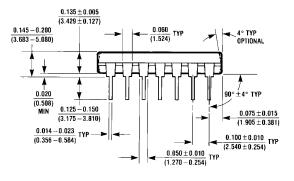
MTC14revD

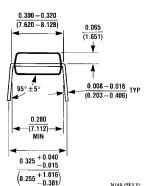


14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)







14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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